

# N x 3.125 Gbps Multi-Mode VCSEL Array

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**AVALON**  
PHOTONICS

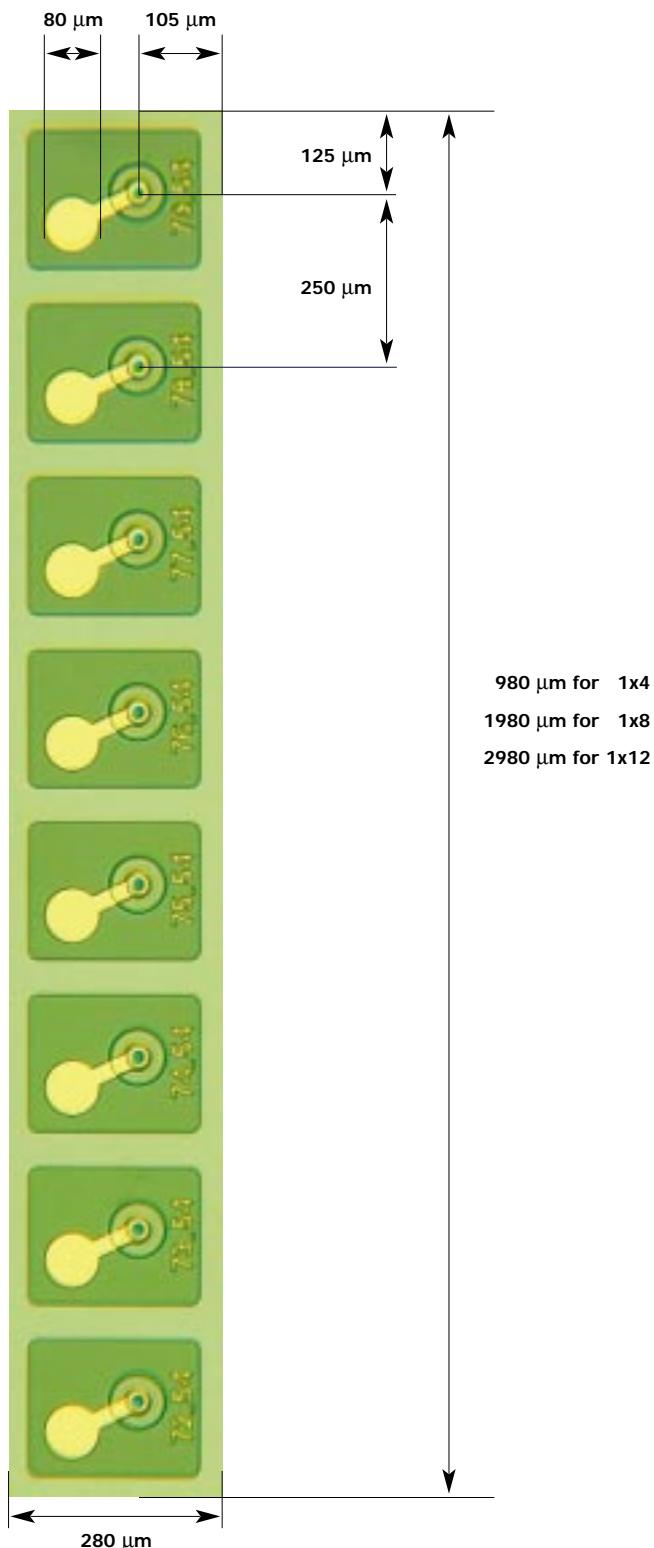
## Features

- 850nm wavelength range
- High wavelength uniformity
- Data rates up to 3.5 Gbps
- Low threshold current

## ● Ordering information

Part Number	Description
APA7201020000	850nm multi-mode array 1x2
APA7201040000	850nm multi-mode array 1x4
APA7201080000	850nm multi-mode array 1x8
APA7201120000	850nm multi-mode array 1x12

Other configurations available on request



**N x 3.125 Gbps  
Multi-Mode  
VCSEL Array**

**Electro-optical characteristics** (for individual lasers)

Parameter*	Symbol	Conditions	Ratings			Units
			Min	Typ	Max	
Optical output power	Pout	Iop = 6 mA		2.1		mW
Threshold current	Ith		1.0	1.8	2.5	mA
Operating voltage	Vop	Iop = 6 mA		1.9		V
Emission wavelength	$\lambda$	Iop = 6 mA	840	850	860	nm
Spectral bandwidth, RMS	$\Delta\lambda$	Iop = 6 mA		0.85		nm
Slope efficiency	$\eta$	Iop = 6 mA		0.5		mW/mA
Beam divergence	$\theta$	Full width, $1/e^2$ , Iop = 6 mA		27	30	$^\circ$
Differential resistance	RDiff	Iop = 6 mA	25	40	50	$\Omega$
Capacitance	C	Iop = 6 mA		0.6	0.9	pF
Bandwidth	f3dB	Iop = 6 mA	3.5	5		GHz
Threshold uniformity**	$\Delta I_{th}$				0.3	mA
Slope efficiency uniformity**	$\Delta \eta$				0.1	mW/mA

**Thermal characteristics**

Parameter	Symbol	Ratings			Units
		Min	Typ	Max	
Temperature tuning coefficient	$\delta\lambda/\delta T$		0.06		nm/K
Threshold current variation 0 to +70°C	$\Delta I_{th}$		1		mA

**Absolute maximum ratings**

Parameter*	Rating	Units
Optical output power	6	mW
Peak forward current	10	mA
Reverse voltage	5	V
Operating temperature	-20 to +85	°C
Storage temperature	-40 to +100	°C

\*(T=25°C unless otherwise noted)

\*\* tighter uniformity specification available on request



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The above specifications are subject to change without notice

